



Dual P-Channel 2.5-V (G-S) MOSFET

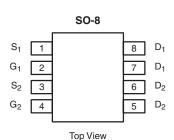
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
- 20	0.032 at V _{GS} = - 4.5 V	- 6.5			
	0.050 at V _{GS} = - 2.5 V	- 5.2			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Compliant to RoHS Directive 2002/95/EC

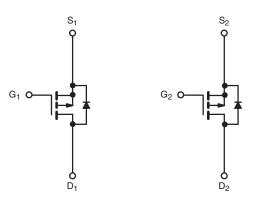


FREE



Ordering Information: Si4963BDY-T1-E3 (Lead (Pb)-free)

Si4963BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	- 20		V
Gate-Source Voltage		V _{GS}	± 12		V
Continuous Drain Current /T 150 °C\2	T _A = 25 °C	I _D	- 6.5	- 4.9	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 5.2	- 3.9	
Pulsed Drain Current		I _{DM}	- 40		Α
Continuous Source Current (Diode Conduction) ^a		I _S	- 1.7	- 0.9	
Mariana Baran Birahadian	T _A = 25 °C	- P _D	2.0	1.1	W
Maximum Power Dissipation ^a	T _A = 70 °C] '`D	1.3	0.7	"
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manifestore bounding to Aughing 18	t ≤ 10 s	R_{thJA}	58	62.5	
Maximum Junction-to-Ambient ^a	Steady State	□thJA	91	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	34	40	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm.

Vishay Siliconix



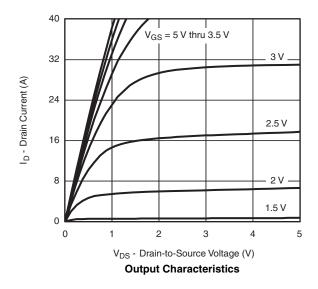
Parameter	Symbol	Test Conditions	Test Conditions Min.		Max.	Unit
Static				'	<u> </u>	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$ - 0.6			- 1.4	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA
Zava Cata Valta da Duais Courset	1	V _{DS} = - 20 V, V _{GS} = 0 V		-1		^
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$	- 5		- 5	μΑ
On-State Drain Current ^a	-State Drain Current ^a $I_{D(on)}$ $V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$		- 20			Α
5	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 6.5 A		0.025	0.032	0
Drain-Source On-State Resistance ^a		V _{GS} = - 2.5 V, I _D = - 2 A		0.040	0.050	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 6.5 A		18		S
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.75	- 1.2	V
Dynamic ^b				•		
Total Gate Charge	Qg			14	21	
Gate-Source Charge	Q _{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -6.5 \text{ A}$		2.6		nC
Gate-Drain Charge	Q _{gd}			4.6		
Gate Resistance	R _g	f = 1 MHz		8.3		Ω
Turn-On Delay Time	t _{d(on)}			30	45	
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		40	60	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω		80	120	ns
Fall Time	t _f			55	85	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dI/dt = 100 A/μs		40	80	

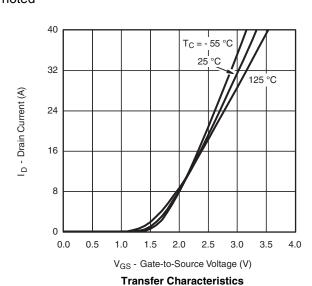
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



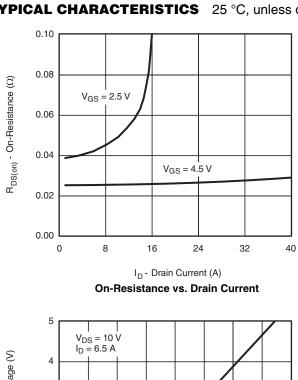


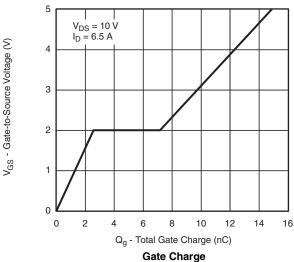


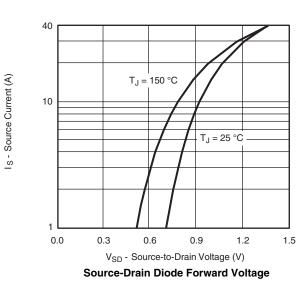


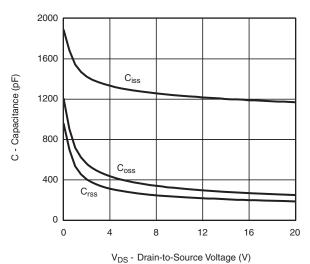


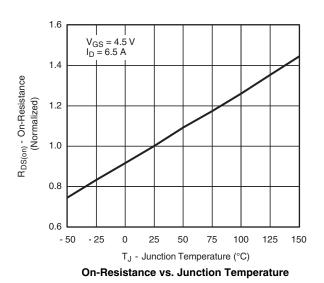
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



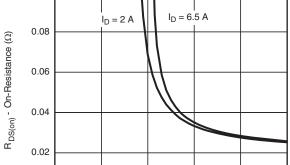








Capacitance



0.10

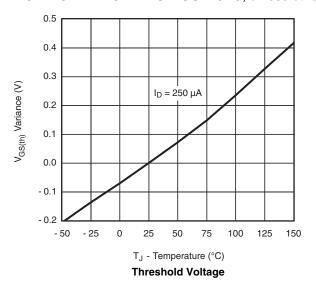
0.00 2 3 4 5 0 V_{GS} - Gate-to-Source Voltage (V)

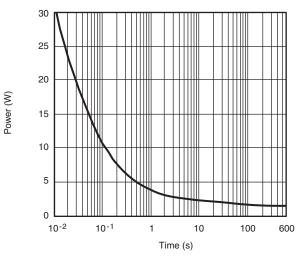
On-Resistance vs. Gate-to-Source Voltage

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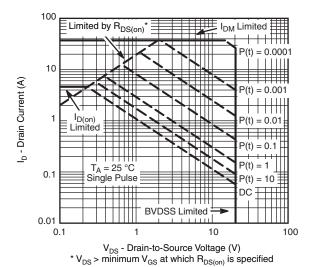
VISHAY.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

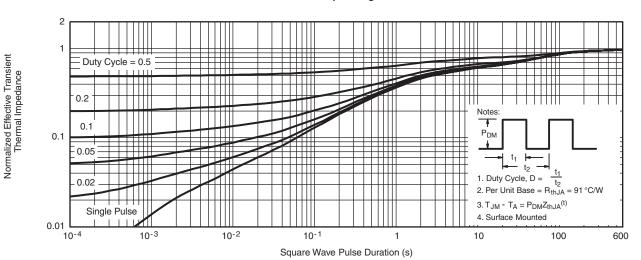




Single Pulse Power



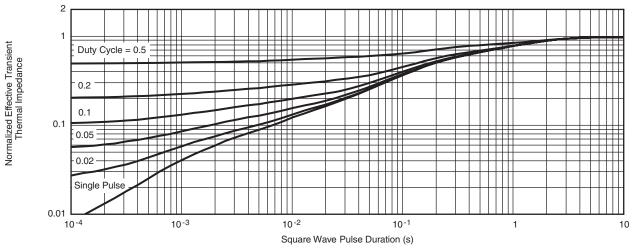




Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72753.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INC	INCHES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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